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# *In situ* scanning tunneling microscopy studies of the SEI formation on graphite electrodes for Li<sup>+</sup>-ion batteries

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The SEI-formation on graphitic electrodes operated as an Li<sup>+</sup>-ion battery anode in a standard 1 M LiPF<sub>6</sub> EC/DMC (1 : 1) electrolyte has been studied *in situ* by EC-STM. Two different modes of *in situ* study were applied, one, which allowed to follow topographic and crystallographic changes (solvent intercalation, graphite exfoliation, SEI precipitation on the HOPG basal plane) of the graphite electrode during SEI-formation, and the second, which gave an insight into the SEI precipitation on the HOPG basal plane in real time. From the *in situ* EC-STM studies, not only conclusions about the SEI-topography could be drawn, but also about the formation mechanism and the chemical composition, which strongly depend on the electrode potential. It was shown that above 1.0 V vs. Li/Li<sup>+</sup> the SEI-formation is still reversible, since the molecular structure of the solvent molecules remains intact during an initial reduction step. During further reduction, the molecular structures of the solvents are destructed, which causes the irreversible charge loss. The STM studies were completed by electrochemical methods, like cyclic voltammetry, the potentiostatic intermittent titration technique and charge/discharge tests of MCMB electrodes.

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## Introduction

Since its discovery in 1979<sup>1</sup> the Solid Electrolyte Interphase (SEI) formation on anodes in non-aqueous batteries has aroused research interest due to its importance for batteries. The batteries can benefit from a proper SEI, as it can increase their cycle life, lifetime, power capability and safety.<sup>2</sup> The SEI builds up a compact surface film on the anode acting as a membrane, being a Li<sup>+</sup>-ion conductor and an electronic insulator.<sup>2,3</sup> The cycle life and lifetime of the battery are extended by the SEI, because of the compact SEI film stabilizing the electrodes against exfoliation and preventing the remaining electrolyte from further decomposition.<sup>4–6</sup>

In recent literature, many different aspects regarding the SEI formation on graphitic electrodes were the focus of research. Publications address fundamental questions ranging from its chemical composition and structure, studied among others by TOF SIMS,<sup>7</sup> SECM,<sup>8–10</sup> SEM, TEM, NMR, XPS, FTIR,<sup>11,12</sup> NSOM<sup>13</sup> to AFM<sup>14–16</sup> and theoretical molecular dynamics studies<sup>17,18</sup> dedicated to the formation mechanism. Besides deepening the fundamental understanding of the SEI, efforts also aim at improving its operating properties by tailoring the chemical composition of the electrolyte taking advantage of additives,<sup>19–21</sup> or by treating the graphite electrodes prior to cell assembly to avoid exfoliation.<sup>22,23</sup>

The SEI-formation is described as a result of the electrochemical reduction of electrolyte components at the anode, including organic carbonate solvents and Li-salts. Cyclic carbonates, such as ethylene carbonate (EC), propylene carbonate (PC) and vinylene carbonate (VC), are reduced *via* the acceptance of an electron and a Li<sup>+</sup>-ion (Scheme 1 (1)), resulting in a ring opening<sup>2,24–28</sup> and the formation of a radical anion<sup>24</sup> (Scheme 1 (2)). In the case of EC, several subsequent reduction pathways are possible: in an overall 1-electron-reduction pathway the electron transfer step is followed by the combination of two radical anions (Scheme 1 (3)), leading to the formation of dialkyl carbonate and ethylene gas (Scheme 1 (4)). This pathway however requires sufficiently low potentials, whereas a 2-electron-reduction occurs already at higher poten-

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## Experimental

Prior to STM experiments, the HOPG samples (MikroMasch, ZYB) were freshly cleaved with adhesive tape leading to a clean and flat basal plane. During the experiments, HOPG served as a working electrode in an electrochemical cell with a surface area of  $0.125\text{ cm}^2$ . The electrolyte used was a solution of 1 M  $\text{LiPF}_6$  dissolved in a 1 : 1 (by volume) mixture of EC/DMC (Solvionics,  $\text{H}_2\text{O} < 20\text{ ppm}$ ). It was further dried by using  $3\text{ \AA}$  molecular sieves (Merck Millipore). Counter and reference electrodes were made from Li-metal (Alfa Aesar, 99.9%). A mechanically cut  $0.25\text{ mm}$  Pt/Ir-wire (80 : 20) (MaTecK) insulated with an electrochemically inert Apiezone® wax (Plano GmbH) was used as a STM tip. The wax was heated up to  $200\text{ }^\circ\text{C}$  during the insulation procedure. The STM tip was held at a potential of  $2.1\text{ V}$  against  $\text{Li/Li}^+$  in all STM measurements. The microscope is a homemade system composed of a PicoSPM STM base (Agilent Technologies®, formerly Molecular Imaging®) with a Pico STM S scanner and a Nanoscope IIIA controller (Veeco Instruments Inc.®). The device is combined with an EC-Tec bipotentiostat/galvanostat BP600 and an EC-Tec biscangenerator SG600. The STM was operated with Nanoscope v5.31.r1 software and the potentiostats were controlled and read out with a labview® program BP600. STM data were evaluated with the WSxM software.<sup>69</sup>

The STM base is placed inside a reinforced Ar-filled (Westfalten, 5.0) glovebox (MBRAUN, MB 200 B glovebox and MB 20G LMF gas purifier) containing a massive granite plate suspended on damping elements, making the glovebox suitable for SPM operation. In addition, the microscope was placed on further rubber damping elements and on another heavy steel block. Moreover, the atmosphere circulation and the vacuum pump of the glovebox were switched off during imaging in order to minimize mechanical disturbance.

Battery tests were conducted in Swagelok® cells consisting of a circular working electrode ( $10\text{ mm}$ ) composed of mesocarbon microbeads (MCMB, TB-17) coated on a Cu-foil ( $9\text{ }\mu\text{m}$ ). The MCMB graphite powder was imaged by using a Zeiss EVO MA10 Scanning Electron Microscope (SEM) and consists of particles with an average diameter of  $17\text{ }\mu\text{m}$  (Fig. 1). The ink for the electrode coating was prepared by mechanically grinding 90% of MCMB as the active material plus 10% of a PVDF (Kynar 900 HSV) binder diluted with NMP solvent in a mortar thoroughly. After coating a  $250\text{ }\mu\text{m}$  film on the Cu-foil and subsequent drying overnight at  $50\text{ }^\circ\text{C}$ , the electrodes were cut using a  $10\text{ mm}$  punch. Thereafter, the electrodes were mechanically pressed with 1 bar pressure in between 2 polished steel stamps (Mauthe Maschinenbau, KBr-press PE-011). Finally, the electrodes were vacuum dried at  $120\text{ }^\circ\text{C}$  for 2 h (Büchi Glass Oven B-585) and transferred to an Ar-filled glovebox for storage and cell assembly. Again, circularly-cut Li-metal sheets were used as counter ( $10\text{ mm}$ ) and reference electrodes ( $6\text{ mm}$ ). In order to prevent direct contact between the electrodes, glass fiber separators (VWR collection, particle retention:  $1.6\text{ }\mu\text{m}$ ) were sandwiched between them. Also, the separators were soaked with a  $40\text{ }\mu\text{L}$  electrolyte (1 M  $\text{LiPF}_6$  in

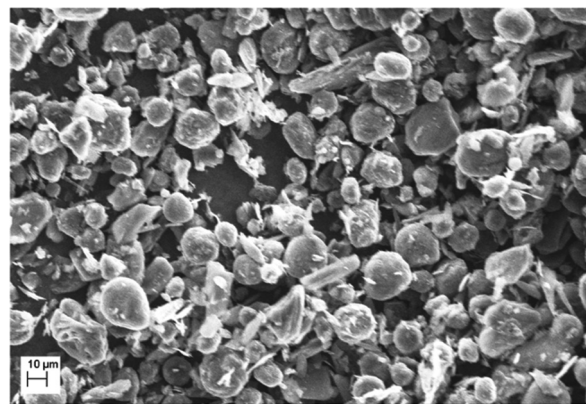


Fig. 1 SEM micrograph of the mesocarbon microbeads.

EC/DMC (1 : 1)) each, serving as an electrolyte reservoir. The total electrolyte content in one cell amounts to  $120\text{ }\mu\text{L}$ . The battery tests were performed with Gamry® potentiostats (Interface 100) with the Gamry Instruments Framework Data Acquisition Software (Version 6.10).

## Results

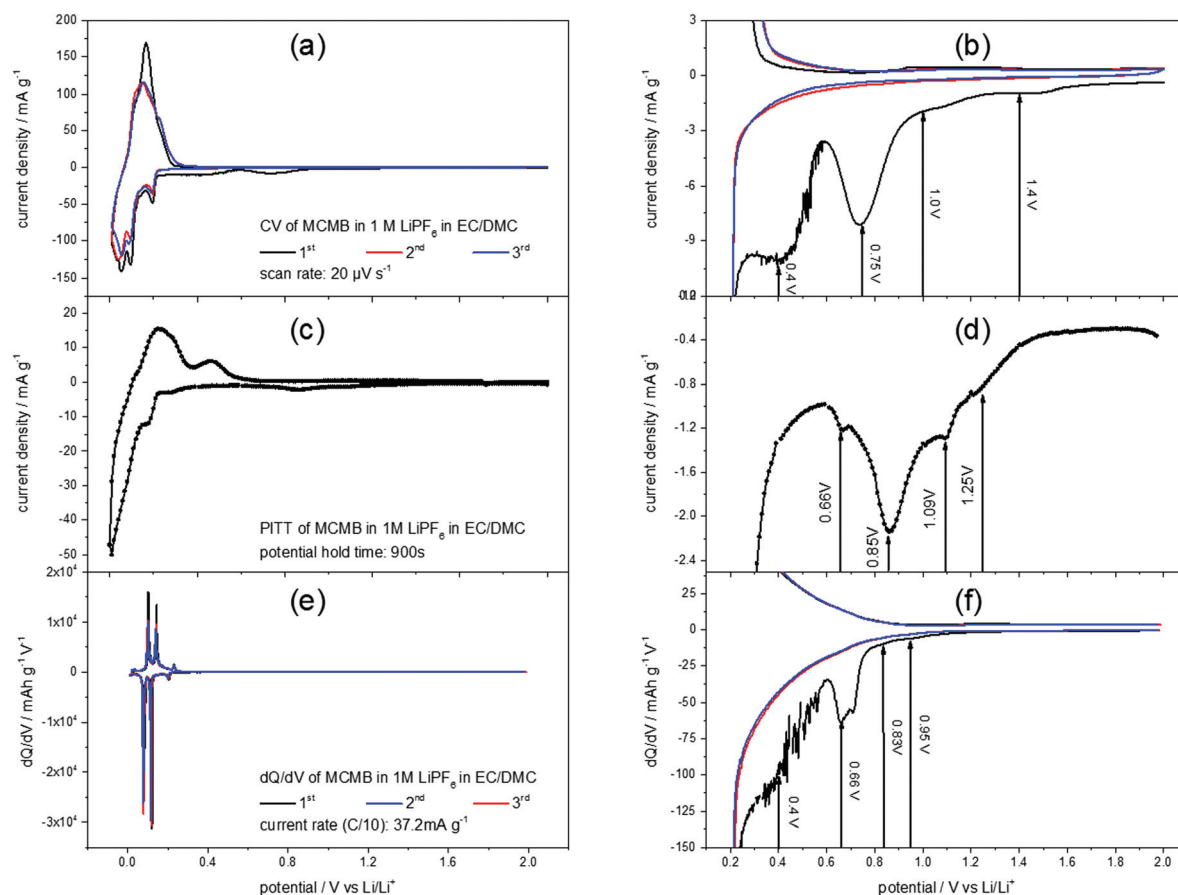
### Electrochemistry

Fig. 2(a) shows a slow scan rate cyclic voltammogram (CV) of a MCMB anode in 1 M  $\text{LiPF}_6$  in EC/DMC. The reversible  $\text{Li}^+$ -ion intercalation, ranging from  $0\text{ V}$  to  $0.3\text{ V}$ , clearly shows the aptitude of graphite as a low voltage anode material. For the discussion of the SEI-formation, however, the high potential region of the CV is of interest (Fig. 2(b)). The difference between the first and the consecutive scans is obvious: the first cycle shows unique features in the cathodic scan while the second and the third scans almost match each other. These features include higher currents throughout the entire potential range, as well as a shoulder at  $1.4\text{ V}$ , followed by another shoulder at  $1.0\text{ V}$  flanking a peak at  $0.75\text{ V}$ . Around  $0.4\text{ V}$  another peak appears, before the  $\text{Li}^+$ -ion intercalation starts. No corresponding anodic features appear, supporting the irreversible character of the processes during the first cycle.

In order to complete the understanding of the electrochemical processes during SEI-formation, the potentiostatic intermittent titration technique (PITT) was applied. Fig. 2(c) and (d) show a PITT-diagram of a MCMB-anode in 1 M  $\text{LiPF}_6$  in EC/DMC, where the electrode potential was stepwise changed from  $2.0\text{ V}$  to  $0.01\text{ V}$  and back to  $2.0\text{ V}$  in  $10\text{ mV}$  steps. After each potential step a current transient was recorded for 15 minutes, followed by a 15 minutes rest at OCP. The PITT-diagram shows the current density of every transient after 15 minutes plotted against the applied electrode potential.

Similar to the CV of MCMB (Fig. 2(a) and (b)), the PITT curve reflects the lithiation/delithiation peaks in the low potential region and the multiple steps of SEI-formation in the high potential region. As in the CV of MCMB, the SEI-formation leads to a shoulder at  $1.25\text{ V}$ , followed by another



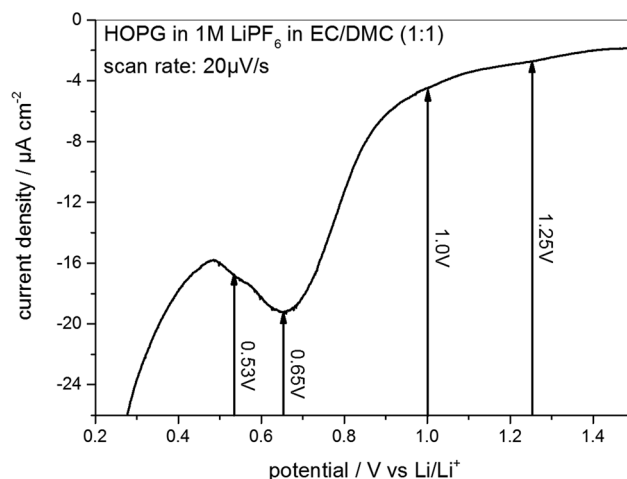


**Fig. 2** Voltammograms of MCMB in 1 M LiPF<sub>6</sub> in EC/DMC (1 : 1) measured by (a and b) cyclic voltammetry (potential sweep rate: 20  $\mu\text{V s}^{-1}$ ) and by (c and d) the potentiostatic intermittent titration technique. For the latter method, the potential was stepwise changed from 2.0 V to 0.01 V and back to 2.0 V in 10 mV steps. After each potential step a current transient was measured for 15 minutes, followed by 15 minutes rest at OCP. The PITT-diagram shows the current density of every transient recorded after 15 minutes at the respective potential. The voltammogram in (e) was derived from a dQ/dV-plot of a charge/discharge curve at a current density of 0.372 mA g<sup>-1</sup> (C/10). (b), (d) and (f) show the magnifications of the CV, PITT and dQ/dV-plot, respectively, in the SEI-formation regime.

shoulder at 1.09 V. Then, the main SEI-peak is found at 0.85 V, accompanied by a shoulder at 0.66 V.

Also from a dQ/dV-plot (Fig. 2(e) and (f)), which was derived from the first three charge/discharge-cycles of a MCMB electrode in 1 M LiPF<sub>6</sub> in EC/DMC at a current density of 37.2 mA g<sup>-1</sup>, corresponding to a rate of C/10, similar findings can be obtained. As in the CV (Fig. 2(a) and (b)) and in the PITT-diagram (Fig. 2(c) and (d)), the dQ/dV-plot shows the Li<sup>+</sup>-ion intercalation/deintercalation in the low potential region. The SEI-formation shows the previously found features, which are a shoulder at 0.95 V, followed by another shoulder at 0.83 V. Then a peak at 0.66 V appears, while the last SEI-formation step occurs in a potential range below 0.6 V. This last step of SEI-formation is associated with a higher level of noise, as can be seen in Fig. 2(b) and (f).

As the STM experiments had to be conducted on a HOPG electrode, a CV of HOPG in 1 M LiPF<sub>6</sub> in EC/DMC was measured in order to guarantee a similar electrochemical behavior (Fig. 3). In comparison to the voltammograms of MCMB (Fig. 2), HOPG shows almost the same SEI-formation



**Fig. 3** SEI formation region of a cyclic voltammogram of HOPG in 1 M LiPF<sub>6</sub> dissolved in EC/DMC (1 : 1). Potential sweep rate: 20  $\mu\text{V s}^{-1}$ .





behavior. The first shoulder appears at a potential of 1.25 V, followed by the second shoulder at the foot of the main SEI peak at 1.0 V. The peak potential of the pronounced main peak shifts to lower potentials compared to MCMB (Fig. 2(b)), which is found at 0.65 V for HOPG. Similar to the PITT voltammogram (Fig. 2(d)), the last peak in the CV of HOPG at 0.53 V is not as clearly pronounced as in the CV of MCMB (Fig. 2(b)).

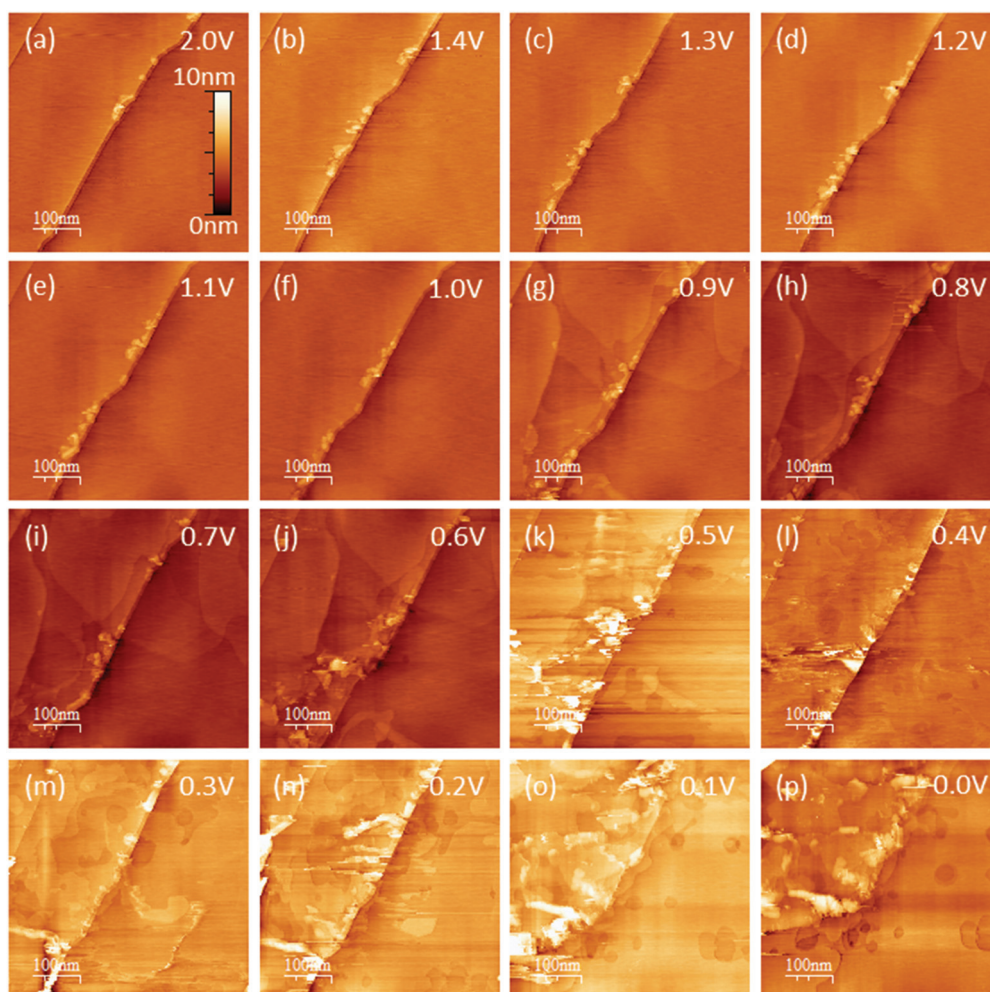
In summary, the voltammograms of MCMB (Fig. 2) as well as the CV of HOPG (Fig. 3) show similar features indicating that the SEI forms in four major steps. In addition, their similarity also implies that one can very well compare the SEI-formation on HOPG and on MCMB and draw the same conclusions for both systems.

### EC-STM

EC-STM as a powerful *in situ* technique was used in the following to complement the electrochemical understanding of the SEI-formation on graphite anodes in carbonate based electro-

lytes for Li<sup>+</sup>-ion batteries. In the first experiment, EC-STM imaging of the SEI-formation on a HOPG electrode in a 1 M LiPF<sub>6</sub> in EC/DMC solution was conducted *in situ* but at a fixed potential of 2.0 V. Fig. 4 shows a series of STM images, always recorded at the same position. The experiment was conducted as follows: first, a STM image (Fig. 4(a)) was measured of the pristine HOPG surface, while the potential was held at 2.0 V, which was well above the onset potential of the SEI-formation. Then, a voltammetric cycle of the sample was carried out from 2.0 V to 1.4 V and back to 2.0 V with a potential sweep rate of 5 mV s<sup>-1</sup> (Fig. 5). Thereafter, another STM image was measured at the same position as before. This procedure was repeated, while the lower vertex potential of the CV was step-wise lowered by 0.1 V.

Hence, the STM images in Fig. 4 always show the HOPG surface after they had been polarized to the potential indicated in every image. As can be seen from the images of Fig. 4(a)–(f), no changes are visible on the HOPG surface above 1.0 V. One



**Fig. 4** EC-STM images of HOPG in 1 M LiPF<sub>6</sub> dissolved in EC/DMC (1 : 1) at 2.0 V. The upper left image shows the pristine HOPG sample, followed by images of the same location after polarization to different lower potentials ((a) 2.0 V, (b) 1.4 V, (c) 1.3 V, (d) 1.2 V, (e) 1.1 V, (f) 1.0 V, (g) 0.9 V, (h) 0.8 V, (i) 0.7 V, (j) 0.6 V, (k) 0.5 V, (l) 0.4 V, (m) 0.3 V, (n) 0.2 V, (o) 0.1 V, (p) 0.0 V). Scan size: 500 nm by 500 nm; tunneling current: 500 pA; tip potential: 2.1 V; sample potential: 2.0 V; bias: 100 mV; tip velocity: 0.5  $\mu\text{m s}^{-1}$ .



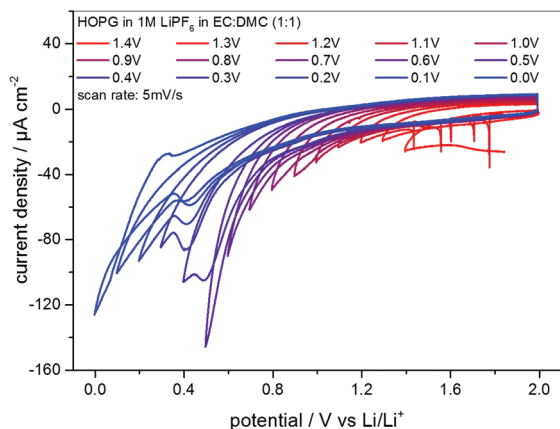


Fig. 5 Series of CVs of HOPG in 1 M LiPF<sub>6</sub> dissolved in EC/DMC (1:1). The lower vertex potential was decreased stepwise from 1.4 V to 0.0 V. Potential sweep rate: 5 mV s<sup>-1</sup>.

sees largely extended, atomically flat terraces, which are interrupted by a 2 nm step edge running diagonally through the image from the bottom left to the upper right. Since the interplanar spacing between two adjacent graphene layers in a graphite crystal amounts to 3.35 Å,<sup>70</sup> this step edge consists of 6 graphene layers. Exfoliated graphene flakes decorate these step edges. In the upper left corner of the images, a mono-atomic step is visible.

Once a potential of 0.9 V was applied to the sample (Fig. 4(g)), irreversible changes in the topography are visible. One can see that large areas on the terraces of the HOPG have swelled. These features are located inside different graphene layers, since they overlap each other. When the potential is further lowered, the swollen regions spread out and grow in size.

In Fig. 4(j), *i.e.* after a potential of 0.6 V has been applied, one can observe a roughening of the surface, caused by a partial exfoliation of graphene flakes along the step edge. This effect becomes more severe at even lower potentials, where big parts of the terrace are removed from the electrode surface and holes appear. At the same time, one can see that the STM images become noisy from 0.5 V and below, which, as will be shown later, is caused by a SEI-precipitation on the HOPG basal plane.

The CVs measured in between every STM image are shown in Fig. 5, where the lower vertex potential was decreased stepwise from 1.4 V (red line) to 0.0 V (blue line). One feature that immediately catches one's eyes is the fact that apart from the CV measured down to 0.0 V, no anodic peaks appear in the reverse scans. This again is a clear indication for an irreversible charge loss due to the SEI-formation. Moreover, the said CV ranging down to 0.0 V is the only CV showing a crossover of the cathodic and the anodic sweep.

Additionally, the currents steadily decrease scan by scan in the SEI-forming potential region, and include a barely visible cathodic shoulder at 1.0 V and a cathodic peak first appearing in the CV measured down to 0.4 V, located at 0.48 V. Also, the onset potential of the SEI formation as well as the peak posi-

tion of the said peak shifts to lower values. Both findings can be explained by the SEI forming over time, always consuming less charge from cycle to cycle, since the growth rate slows down as the thickness and hence the tunneling resistance of the electrons through the SEI increase.

These EC-STM studies gave some interesting preliminary results, but suffered from two shortcomings: first it is impossible to draw any conclusions about the time scales of the processes happening at the surface and secondly, reversible processes only present at low potentials, *i.e.* potentials far below 2.0 V, where the STM images were recorded, cannot be visualized. These issues were solved by redesigning the STM experiment. Fig. 6 also shows an *in situ* STM study, where the imaging was carried out in parallel to the variation of the electrode potential, in contrast to the experiment before, where imaging and CV were performed sequentially. This way, it is possible to obtain insight into the time scales of surface processes and to see changes of the electrode surface only occurring while low potentials are applied.

Fig. 6 shows three 3D-STM images of a HOPG electrode. Since STM images are acquired by scanning the surface line by line, one can arrange the images in a way that they match with a time axis running from left to right. Simultaneous to STM-imaging, a potential was applied to the electrode. The time scale of the applied potential can be synchronized to the time axis of the STM experiment. This way, one can overlay the

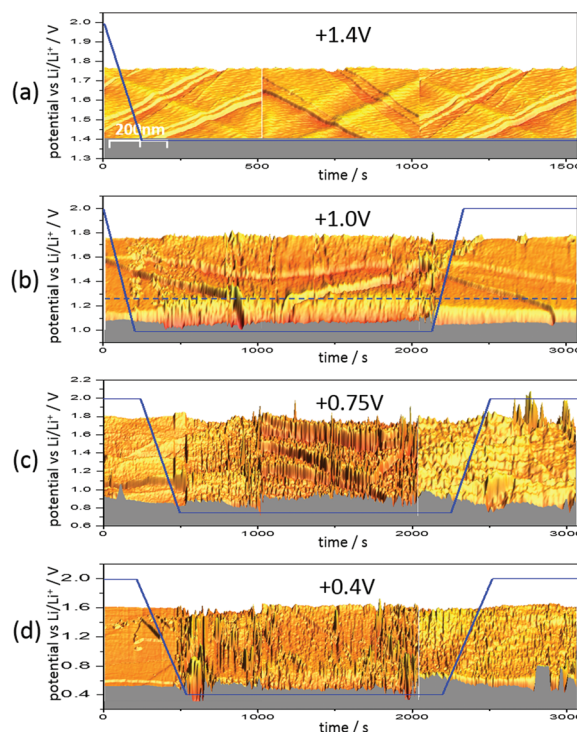


Fig. 6 *In situ* real time EC-STM images of HOPG in 1 M LiPF<sub>6</sub> in EC/DMC (1:1). The x-axis was converted to a time axis. Scan size: 500 nm by 500 nm; tunneling current: 500 pA; tip potential: 2.1 V; bias: variable; tip velocity: 1 μm s<sup>-1</sup> for the experiment at 1.4 V and 0.5 μm s<sup>-1</sup> for the other experiments; potential sweep rate: 5 mV s<sup>-1</sup>.



potential scan and the STM scan and obtain a real time insight into potential-dependent surface processes, provided these processes cause a change in surface morphology detectable by STM.

Fig. 6(a) shows the HOPG surface, while the electrode potential (blue line) was lowered with  $5 \text{ mV s}^{-1}$  from 2.0 V to 1.4 V, where the potential was then held. The HOPG surface is atomically flat on largely extended terraces, which are traversed by several step edges, partially only being one atom high. Otherwise, the surface remains smooth and clean throughout the measurement (*ca.* 25 min).

The situation changed, if one repeated such an experiment applying a holding potential of 1.0 V (Fig. 6(b)). One can see that the HOPG surface is atomically flat in the very beginning of the experiment. Just when the potential is in the range between 1.3 V and 1.2 V, a surface film precipitation on the HOPG basal plane becomes visible. The film thickness as determined by STM increases with time until it reaches some limit. Interestingly, this surface film disappears again, once the electrode potential is driven to higher values. The blue dashed line depicts the place, along which a height profile was measured (Fig. 7). From this profile, one can estimate the film thickness and better comprehend the time scales. The film growth lasts about 200 s, until a final detected thickness of about 2 nm is reached. The shown profile is a representative example for other positions in Fig. 6(b).

Next, the potential was lowered to 0.75 V (Fig. 6(c)). In the beginning, the surface is smooth again, until the potential is low enough to lead to a surface film precipitation. In contrast to the previous experiment, the surface film does not disappear after increasing the potential again.

Since the voltammograms (Fig. 2 and 3) proposed four steps of SEI-formation with the last step occurring at potentials as low as 0.6 V, another STM experiment was conducted even at this potential (Fig. 6(d)). However, no new information compared to the measurement at 0.75 V can be obtained (Fig. 6(c)). Similar to the height profile indicated by the line in Fig. 6(b) and shown in Fig. 7, the SEI thickness can also be estimated

for the data shown in Fig. 6(c) and (d). The analysis results in analogical values and hence is not shown here.

## Discussion

The CV of MCMB (Fig. 2(a) and (b)), the corresponding PITT measurement (Fig. 2(c) and (d)), the  $dQ/dV$ -plot (Fig. 2(e) and (f)) and the CV of the HOPG sample (Fig. 3) all indicate that the SEI-formation is a multistep process. As was already proposed in the literature, the SEI-formation is initiated by the reduction of the carbonate molecules. Both, linear<sup>30,31</sup> and circular<sup>24,29–31,37</sup> carbonates can either undergo a 1-electron-reduction or a 2-electron-reduction, depending on the applied electrode potential, while the circular carbonates first need to undergo a ring-opening step. Preceding the actual SEI formation, the double layer establishment, which is a re-coordination of the solvation shell around the  $\text{Li}^+$ -ions in the outer Helmholtz plane, is initiated at potentials above 1.4 V and described in detail in ref. 71, followed by the ring-opening during the EC molecule reduction.<sup>29,37</sup> The cathodic shoulder in the potential sweeps on MCMB at 1.4 V, 1.25 V and 0.95 V (Fig. 2(a), (b) and (c), respectively) and on HOPG at 1.25 V (Fig. 3), can probably be ascribed to the double layer establishment. Below 1.0 V the reduction of the solvent molecules proceeds *via* the 2-electron-pathway,<sup>2,32,37,72–75</sup> which changes over to the 1-electron-reduction at 0.8 V.<sup>29,37</sup> Only at very low potentials close to 0.4 V, the reduction strength of the electrode is strong enough to also reduce the  $\text{Li}_x\text{PF}_y$ .

By electrochemical STM the multistage nature of the SEI formation can also be revealed. The experimental procedure that was used to obtain the images shown in Fig. 4, has been applied earlier in similar studies<sup>14,58–67</sup> and allows one to image the cointercalation of  $\text{Li}^+$ -ions together with their solvation shell, exfoliation processes and the SEI precipitation on the graphite basal plane. As is often reported in the literature, the SEI starts to precipitate on the graphite edge, due to the increased reactivity towards electrolyte reduction,<sup>40,56,57</sup> which might explain the observed step edge roughness caused by the initialization of SEI precipitation along the more reactive step edges. However, the observed roughness is already present on the pristine sample, it does not change when going to lower potentials and it was not observed in all STM experiments carried out. Thus, as mentioned earlier, one probably sees exfoliated graphene sheets decorating the step edges. The STM data does not give any hint towards an increased SEI-formation reactivity along the step edges compared to the basal plane. In addition, STM is not feasible on graphite cross-sections, which does not allow for a direct comparison between basal- and cross-sectional SEI-formation.

The simultaneous intercalation of  $\text{Li}^+$ -ions and their solvation shell is the origin of the swellings observed in the STM images (Fig. 4(g)) after polarizing the sample to 0.9 V. This finding is in accordance to Inaba's early STM work, where a cointercalation was observed in similar electrolytes at potentials close to 1.0 V.<sup>58–60</sup>

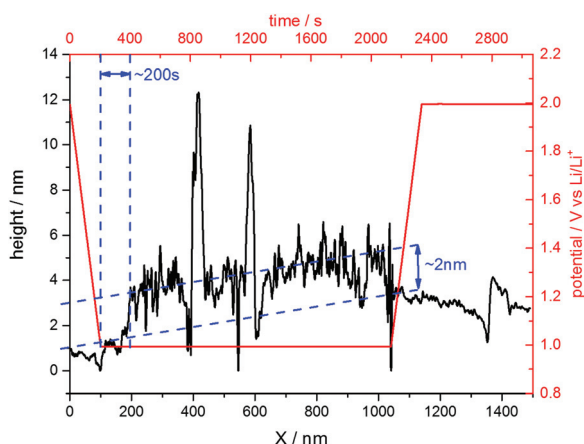


Fig. 7 Height profile across the SEI-film along the blue line depicted in Fig. 6(b).





The exfoliation, which becomes visible below 0.6 V (Fig. 4(j)) can have two origins: one is the mechanical stress induced from the cointercalated species<sup>35,58–61,63–65,68</sup> and the other one is a subsurface gas evolution resulting from the electrochemical reduction of the cointercalated solvent molecules.<sup>3,5,14,59–61,64,76–80</sup> Most of the studies in the literature examine the propylene gas evolution being associated with the reduction of PC, which is much more severe compared to the ethylene gas evolution from the EC reduction.

From 0.5 V and below (Fig. 4(k)) the STM images become slightly fuzzy. At this stage of the SEI-formation, the SEI-film on the graphite basal plane changes its nature from organic (oligomers, polymers) to one containing more inorganic species (oxides, fluorides, phosphates).<sup>2,39,50–53</sup> The organic species, which are comparably soft, can be in part penetrated by the STM tip, which just pushes through to the HOPG basal plane. Thus, the organic surface film present at high potentials does not affect the STM measurements much. Only when the organic species are further reduced to more rigid inorganic species, the electron tunneling between the sample and tip is strongly disturbed and the imaging of the basal plane is affected by noise, which causes the fuzziness.

A similar fuzziness was also noticed by Wang *et al.*<sup>65</sup> The complete reduction of the SEI species and the formation of the inorganic species represents the last stage of SEI formation and assumably causes the low voltage SEI-peak in the voltammograms in Fig. 2(b) and (d) for a MCMB electrode at 0.4 V and at 0.66 V and in Fig. 3 at 0.53 V for a HOPG electrode.

The CVs in Fig. 5 show the continuous irreversible charge consumption during the cathodic sweeps. The crossover of the anodic and the cathodic sweep below 0.1 V in the scan down to 0.0 V and the subsequent appearance of an anodic peak at 0.3 V indicate a reversible Li-plating/stripping onto the HOPG basal plane. In the same potential range a reversible Li<sup>+</sup>-ion intercalation/deintercalation should occur, at least in a MCMB electrode, however, due to the low quantity of step edges on HOPG, which offer the required diffusion channels, it is believed that the intercalation/deintercalation is suppressed and does not show up in the CVs.

Fig. 6 gives a very detailed insight into the characteristics of SEI-formation in dependence of potential and time. In Fig. 6(a), the sample potential was set to 1.4 V, which was motivated by the first shoulder corresponding to the double

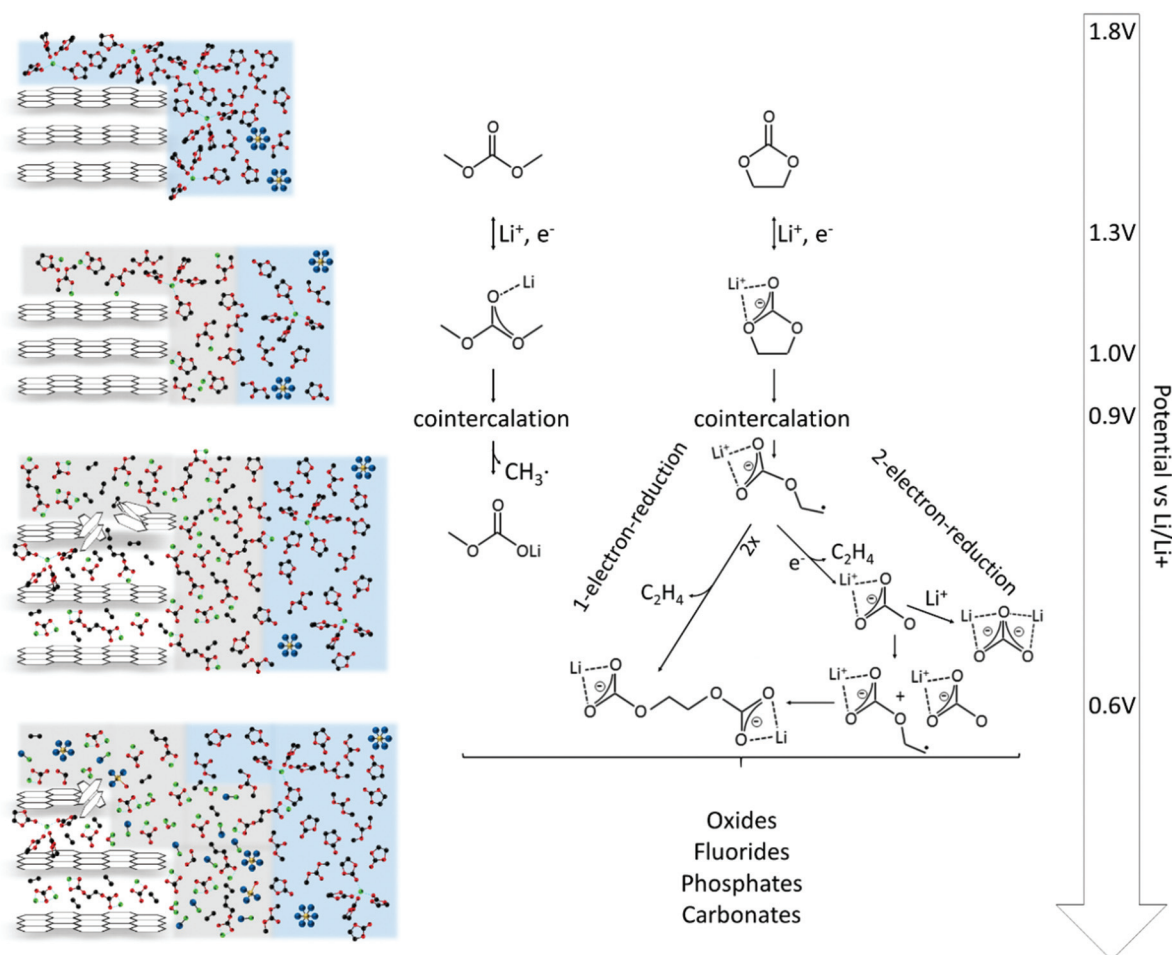


Fig. 8 Scheme of the SEI formation on graphite anodes in carbonate based electrolytes.





layer establishment appearing at this potential in the voltammograms (Fig. 2 and 3).<sup>29,37</sup> This double layer establishment is, of course, not observable by STM and hence the HOPG surface stays unaltered.

In contrast to the double layer establishment, a surface film forming between 1.3 V and 1.0 V in Fig. 6(b) is detectable by STM and has a reversible nature, meaning that it disappears again at high potentials. The surface film probably originates from the adsorbed reaction products of the first reduction step of the EC molecule (Scheme 1 (1)), which causes the shoulder of the voltammograms in Fig. 2 and 3 at 1.0 V and 1.09 V. This reaction can be assumed to be fully reversible, which would be in accordance to the reversible character of the SEI above 1.0 V observed in Fig. 6(b). The same argumentation holds true for the first reduction step of DMC (Scheme 2 (1)).

As can be seen in Fig. 6(c), the graphite basal plane is irreversibly covered by the surface film after polarizing the graphite electrode to 0.75 V. This behavior can be explained, considering the next reaction steps in Schemes 1 and 2. In both reactions the structure of the original molecule is irreversibly destroyed by the ring opening and the dissociation of ethylene gas of the EC molecule or the fragmentation of the DMC molecule. Thus, the main SEI peaks at 0.75 V, 0.85 V, 0.66 V and 0.65 V in Fig. 2(b), (d), (e) and 3, respectively, unify the reduction of DMC to lithium methyl carbonate and the 2-electron- and 1-electron-reduction of EC.

Due to the insensitivity of STM towards discrimination of chemical species, not many conclusions can be drawn from Fig. 6(d). It is known from the literature that at such low potentials as 0.4 V also the Li-salt anion, *i.e.*  $\text{PF}_6^-$ , can be reduced leading to the formation of a variety of fluorides, oxides, phosphates and further inorganic species.<sup>2,15,24,25–28,30</sup>

The last point to be discussed is the height profile measured across the SEI in Fig. 6(b). Since STM does not solely detect the sample topography but is also affected by the electronic states of the sample and the tip, the obtained 'height' information is a convolution of both (see for instance ref. 81). Moreover, the SEI is partially composed of soft, non-conductive polymers, which cannot be detected easily by the STM tip. Hence, the surface film visible in Fig. 6 only shows parts of the SEI and also the height profile in Fig. 7 does not show the full thickness of the SEI. Instead, it rather represents the lower limit of the SEI thickness.

## Conclusions

In this work, the SEI formation on graphitic electrodes in 1 M  $\text{LiPF}_6$  in EC/DMC was studied by electrochemical methods, including cyclic voltammetry and potential step techniques, as well as by scanning tunneling microscopy. Both studies, electrochemistry and microscopy, have been proven to complement each other, yielding new mechanistic and topographic insights into the SEI formation.

Fig. 8 summarizes the findings discussed above and puts them in relation to the electrode potential. The SEI-formation

is initialized by the double layer establishment.<sup>29,37</sup> In the potential range between 1.3 V and 1.0 V the solvent molecules undergo their first reduction, leading to a reversible film deposition on the substrate.

Afterwards, a cointercalation of  $\text{Li}^+$ -ions and solvent molecules is observed, already at 0.9 V (Fig. 4(g)). It is, however, unclear, how the cointercalation proceeds in terms of the solvent coordination around the  $\text{Li}^+$ -ions. How large is the coordination number  $n$ , usually ranging from one to five in the bulk electrolyte,<sup>25,82–84</sup> of the  $\text{Li}^+(\text{EC})_n$  supermolecule upon cointercalation into the graphite lattice?

In the course of further reduction the molecular structure of the solvents is irreversibly destroyed by *e.g.* EC ring opening. In that case two potential dependent mechanisms are possible, a 2-electron-reduction at higher potentials<sup>2,24,29–32,36,37,72–75</sup> and a 1-electron-reduction at lower potential,<sup>24,29–31,36,37</sup> leading to the irreversible deposition of a surface film (Fig. 6(c)).

Below 0.6 V the reduction strength is strong enough to form a complex multicomponent mixture of inorganic compounds like oxides, fluorides, phosphates and carbonates,<sup>2,39,50–53</sup> affecting the STM imaging and resulting in increased noise. Since the reduction strength decays with increasing distance from the electrode, these species can only be found in the very vicinity of the electrode.

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